



# **Actuator Driver for Portable CD Players**

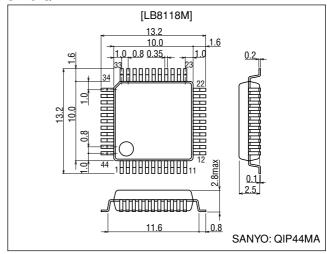
### Overview

The LB8118M is an actuator driver IC designed for portable CD players that operate at 2.4 V (two Ni-Cd batteries) or 3.0 V (two dry cells). Because the four-channel driver control outputs are divided into two groups, this device reduces power dissipation considerably during double-speed play.

# Package Dimensions

unit: mm

#### 3148-QIP44MA



### **Functions and Features**

- H bridge drivers on chip for four channels to drive each CD actuator (the focus coil, the tracking coil, the spindle motor, and the sled motor).
- Step-up circuit (voltage to be set by an external resistor) on chip that is used to apply voltage to the CD DSP, ASP and microcontroller. Center-tap coil for step-up circuit makes it possible to supply the driver control voltage. (However, the drive Tr, L, C, and Di are all external.)
- Oscillator circuits for each converter on chip. (C is external.)
- Four-channel driver control output is divided into two groups (the focus/tracking group and the spindle/sled group) for minimum loss at double-speed playback. Highest operating voltage detected in each group is supplied for each 2ch H bridge driver after PMW conversion. The single channel PWM drive without dividing the outputs into two groups is also possible. (However, the PWM PNP-Tr, NPN-Tr, L, C, and Di are all external.)
- The dynamic range of 4-channel H bridge driver output voltage is up to 2 V on the focus and tracking side, and can be set by the Voset pin on the spindle and sled side. However, if the 4-channel H bridge voltages in the H bridge driver block are the same, the maximum voltage is determined using the Voset pin.
- Sled motor driving mode is switchable between step drive mode for lower power dissipation, and normal V-type drive mode. (The other three channels are fixed to V-type.)
- In the spindle motor drive circuit, the control gain can be set higher for double-speed playback.

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- PWM step-down circuit for external power operates when external power (4 V or higher) is supplied.
  - In this function, external power is converted to V<sub>CC</sub> power supply, and two type voltage setting is possible.
  - In playback mode, step-up voltage for DSP has to be set equal to or lower than  $V_{CC}$ , but in charging the battery, it has to be set higher enough than  $V_{CC}$ .
  - So step-down voltage ( $V_{CC}$ ) setting of two types is possible with two pairs of external resistor. (Switching port is provided.)
  - (However, the PWM PNP-Tr, NPN-Tr, L, C, and Di are all external.)
- APC step-up power supply for the laser diode. (Also supports a pre-power supply for the internal bias.) The laser diode is controlled with a voltage of roughly 0.5 V.
- Battery pulse charging function on chip. (However, the drive NPN-Tr, and the current feedback C and R are external.)
- Battery check comparator on chip.
- The system can be started up and stopped by outputs from the microcontroller.
- Actuator muting function on chip (for all four channels simultaneously).
- Thermal shutdown circuit on chip.

# **Specifications**

## Absolute Maximum Ratings at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub> max		7	V
VCD pin input voltage	V <sub>CD</sub> max		10	V
H bridge output current	I <sub>OUT</sub> max	Maximum per channel is 400 mA.	800	mA
Allowable power dissipation	Pd max	Independent IC	700	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

#### Allowable Operating Ranges at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	Vcc		1.6 to 5.0	V
V <sub>CD</sub> pin input voltage	V <sub>CD</sub>		3.6 to 9.0	V
V <sub>CC</sub> drop setting voltage when external voltage input is applied	V <sub>CC(EXT)</sub>		3 to 5	V
H Bridge limiter voltage	VH LIM		0.15 to 2.25	V

#### Electrical Characteristics at Ta = 25 °C, V<sub>CC</sub> = 3 V, V<sub>CD</sub> = 4 V

Parameter	Symbol	Conditions	min	typ	max	Unit
[Power Supply Block]						
Standby current drain	Icco	$S/S = H$ , the total of $V_{CC}$ and $V_{CD}$			100	μA
V <sub>CC</sub> quiescent current drain	Icc	S/S = L, V <sub>CC</sub> line only		11	15	mA
V <sub>CD</sub> quiescent current drain	ICD	S/S = L, with no driver input		3.5	5.0	mA
[ASP step-up circuit]						
ASP drive output current	IO ASPDRV		2.1	2.5	2.9	mA
VASP pin input bias current	IB VASP				200	nA
ASPBASE pin saturation voltage	Vo aspbase	I <sub>O</sub> = 1 mA		0.1	0.2	٧
Load regulation	RLD ASP	$V_{ASP} = 3.4 \text{ V}, L = 30 \mu\text{H}, C = 220 \mu\text{F}$			1000	mV/A
Line regulation	RLN ASP	$V_{ASP} = 3.4 \text{ V}, L = 30 \mu\text{H}, C = 220 \mu\text{F}$			100	mV/V
Minimum off duty	DMIN ASP			50		%
[APC step-up circuit]						
APC drive output current	IO APCDRV		0.37	0.50	0.63	mA
VAPC pin input bias current	IB VAPC				200	nA
V <sub>APC</sub> – V <sub>LD</sub> voltage	VAPC - LD		0.35	0.50	0.65	٧
Load regulation	RLD APC	V <sub>APC</sub> = 3.4 V, L = 30 μH, C = 220 μF			1000	mV/A
Line regulation	RLN APC	V <sub>APC</sub> = 3.4 V, L = 30 μH, C = 220 μF			100	mV/V
Minimum off duty	DMIN APC			50		%

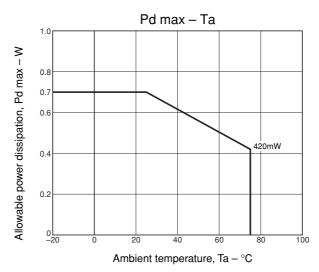
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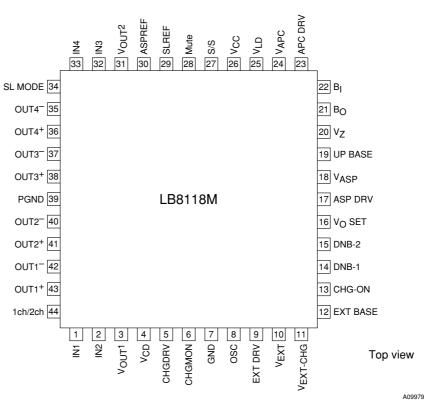
Parameter	Symbol	Conditions	min	typ	max	Unit
[H Bridge Output Block, PWM Block]						
Output saturation voltage	V <sub>H</sub> sat	I <sub>O</sub> = 200 mA, TOP + BOTTOM		0.30	0.45	V
Maximum output voltage	V <sub>PWM</sub> max	V <sub>OUT</sub> 1		1.95	2.25	V
PWM applied offset voltage	VPWMOFF	Each VIN = VASPREF	0.14	0.17	0.22	V
DNB-1,2 pins output voltage	lo DNB1,2			Vout/60		mA
Load regulation	RLD PWM	V <sub>OUT</sub> = 2.25 V, L = 30 μH			1000	mV/A
Line regulation	RLN PWM	V <sub>OUT</sub> = 2.25 V, L = 30 μH			100	mV/V
[Drive Control Block]		·				
CH1 to 4 input voltage range	V <sub>IN</sub> 1–4		0.5	V <sub>CD</sub>	-0.5	V
Input bias current	I <sub>BIN</sub>	Each VIN = VASPREF			2	μA
ASPREF input voltage range	VASPR	Each VIN = VASPREF	1.2	V <sub>CD</sub>	-1.3	·V
CH1,2,4 transfer gain	G124 <sub>IN</sub>	R <sub>L</sub> = 10	6.8	8.0	9.2	dB
CH3 L side transfer gain	G3L <sub>IN</sub>	R <sub>L</sub> = 10	8.5	10.0	11.5	dB
Negative/positive transfer gain difference	G IN	R <sub>L</sub> = 10	-1	0	+1	dB
Input dead zone voltage range	V <sub>DZ</sub>	R <sub>L</sub> = 10	0		30	mV
[SLED Drive Circuit]	- 52	_ ·· · · ·				
SLREF pin input voltage				I		
range	VSLREF		Vaspref+0.1	VcD	-1.0	V
SLREF pin input bias current	IB SLREF				200	nA
Positive side setting offset	IB SLNEF				200	11/3
voltage between IN4 and SLREF	V <sub>off SLREF</sub>	V <sub>SLREF</sub> = 2.3 V, V <sub>ASPREF</sub> = 2 V	-20		+20	mV
Dual side step width difference voltage	V <sub>SLDIF</sub>	V <sub>SLREF</sub> = 2.3 V, V <sub>ASPREF</sub> = 2 V	-20		+25	mV
SL MODE pin high voltage	VH SL MODE		2			V
SL MODE pin low voltage	V <sub>L</sub> SL MODE		-25		+1	V
[OSC Block]			<u> </u>	-	4	
Maximum oscillation frequency	Fosc max				100	kHz
Source current	Is osc	Vosc = 0.0 V		46		μA
[S/S Pin Function]						
S/S start voltage	Vss on			Vcc	-1.0	V
S/S off voltage	Vss off		0.5			V
[External Voltage Input Block]						
Minimum operating input voltage when external voltage input is applied	V <sub>EXT</sub> min	R <sub>IN</sub> = 1 k	3.8			V
EXTDRV pin output current	IO EXT DRV		160	200	240	μA
VZ pin voltage	Vz	V <sub>EXT</sub> = 4.5 V, R <sub>IN</sub> = 1 k		2.6	2.8	V
VZ pin inflow current	IVZ	7 11		-	20	mA
VEXT, VEXT-CHG pin	Iв ехтсна					
Input bias current	IB EXT				200	nA
EXTBASE pin saturation						
voltage	VEXTBASE	$I_O = 1 \text{ mA}$			0.2	V
[Muting Block]						
Mute on voltage	V <sub>ON MUTE</sub>				1	V
Mute off voltage	VON MUTE VOFF MUTE		2			V
[Pulse Charging Function]	V OFF MUTE					٧
Internal reference voltage	Vchgref		0.32	0.35	0.38	V
CHG-ON pin ON voltage			0.32	0.33	0.36	V
CHG-ON pin OFF voltage	Vous off		2		1	V
	V <sub>CHG-OFF</sub>				1	V
CHG-MON pin input bias current	Ів снамол				200	nA
CHGDRV pin output current	IO CHGDRV		2.4	3.0	3.6	mA

Parameter	Symbol	Conditions	min	typ	max	Unit		
[H Bridge 1-channel/2-channel dr	[H Bridge 1-channel/2-channel drive switch]							
1-channel/2-channel switching, 2-channel on voltage	V 1ch/2ch				1	V		
1-channel/2-channel switching, 1-channel on voltage	V 1ch/2ch		2			V		
[TSD Block]								
Operating temperature	T <sub>TSD</sub>	Design target value, Note 1		180		°C		
Temperature hysteresis width	T <sub>TSD</sub>	Design target value, Note 1		20		°C		
[Battery Check Block]								
Input bias current	I <sub>BIN</sub>				200	nA		
Output saturation voltage	V <sub>BO</sub>	Ιο = 100 μΑ			0.3	V		
Battery detection voltage	Vdet			0.7		V		

Note 1: For parameters which have an entry of "design target value" in the "Conditions" column, no measurements are made.



## **Pin Assignment**



# LB8118M

## **Pin Functions**

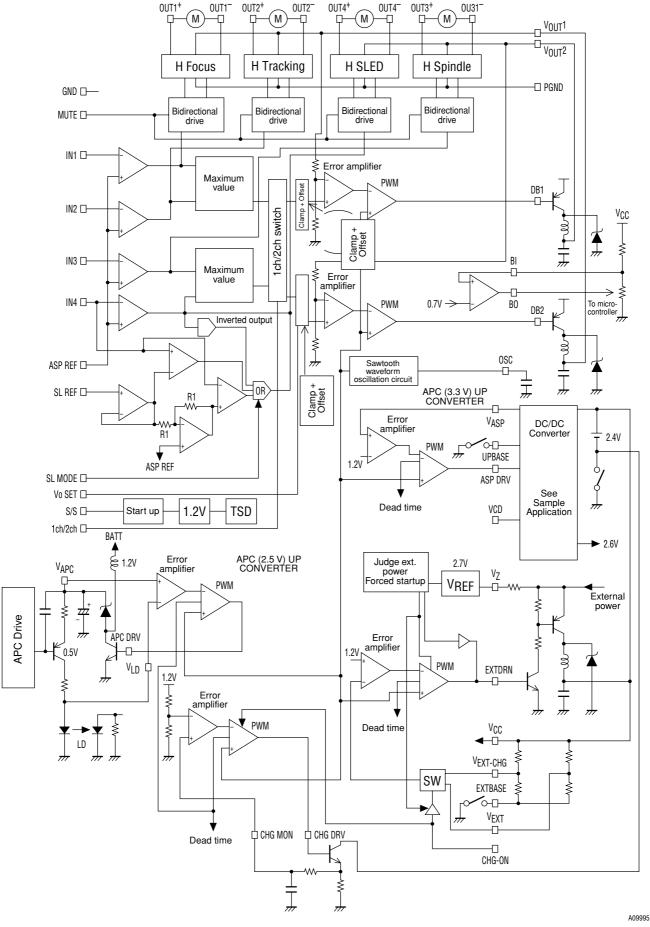
Pin No.	Symbol	Equivalent circuit	Function
1, 2	IN1, IN2	VCD - + +	Actuator control signals for each
32, 33	IN3, IN4	T VCD VCD	driver:
			IN1: Focus, IN2: Tracking,
			IN3: Spindle, IN4: Sled.
		IN1~4 200Ω ]	These signals are input from the
		ASP <sub>REF</sub>	ASP (DSP).
00	A C D	- 13kΩ +	1 1
30	ASPREF		Control reference signal input pin for
		50µA 50µA 777	each driver. This signal is input from the
		<i>m m</i>	ASP (DSP).
		A09980	
40.40	OUT41 4-		
43, 42	OUT1+, 1-	Vcp OUT1/2 vcp	Focus coil actuator drive output pins.
41, 40	OUT2+, 2 <sup>-</sup>	VCD VCD VCD	Tracking coil actuator drive output pins.
38, 37	OUT3+, 3 <sup>-</sup>		Spindle motor drive output pins.
36, 35	OUT4+, 4 <sup>-</sup>	V <sub>CC</sub> V <sub>CC</sub>	Sled motor drive output pins.
			(Each channel includes built-in
			spark killer diodes.)
3	V <sub>OUT</sub> 1	The state of the s	Power supply pins for the H bridge
31	V <sub>OUT</sub> 2		driver. VOUT1 is for the focus/tracking
01	¥0012		group and Vout2 is for the spindle/sled
			group.
			Maximum value + $\alpha$ ( $\alpha$ : saturation
		PGND A09981	voltage of upper/lower output Tr) of each
			2-channel control output is set by
			external PWM step-down circuit.
4	V <sub>CD</sub>		Power supply for the actuator driver
	- 05		controller, maximum value circuit for
			PWM, and sled controller.
5	CHGDRV		Base drive output pin for the external
	OHABITA		NPN-Tr for the battery pulse charging
			circuit.
9	EXTDRV	_	Base drive output pin for the external
9	EXIDAV	Constant-current	
		value of each	step-down NPN-Tr used when external
		VCC + + +	voltage input is applied.
14	DNB-1		Base drive output pin for the PNP-Tr for
		CHGDRV: 3mA  ← EXTDRV: 200 μA	the step-down PWM that generates the
		ASPDRV: 1mA	power supply for the H bridge driver that
		APCDRV: 0.5mA	drives the focus/tracking group
		CHGDRV DNB-1 DNB-2	actuators. (Open when there is one H
		ASPDRV L	bridge power supply.)
15	DNB-2	APCDRV APCDRV	Base drive output pin for the PNP-Tr for
			the step-down PWM that generates the
			power supply for the H bridge driver that
			drives the spindle/sled group actuators.
		Constant-current circuit which changes with the input of CH1 A09982	(DNB-2 becomes the drive pin when
		through 4. (3 mA max)	there is one H bridge power supply.)
17	ASPDRV	+	Base drive output pin for the
''	AOI DITY		external NPN-Tr for the step-up
			circuit that sets the external
	40000		voltage for the DSP.
24	APCDRV		Base drive output pin for
			external NPNTr for the laser diode APC power supply.

Pin No.	Symbol	Equivalent circuit	Function
6	CHG MON	VCC VCC EXTBASE  0.35V 200Ω CHG-MON 50 μA	Constant-current feedback input pin for the charging circuit. Thecharging current is determined by comparing this input voltage and the internal reference voltage (0.35 V typ.).
12	EXTBASE	100kΩ 15μA 15μA 100kΩ 15μA 100kΩ 100kΩ 100kΩ 100kΩ 100kΩ 100kΩ	Connection pin for the resistor that is used to set the voltage for the external step-down circuit.  This prevents invalid current at no power supply.
7	GND		LB8118M GND pin for small-signal block. (GND except output power Tr)
8	OSC	V <sub>CC</sub>	Input pin for the free-running oscillation circuit that is used to operate the PWM step-down circuit and step-up circuit. The oscillating frequency is determined by external capacitors.
10	V <sub>EXT</sub>	V <sub>CC</sub> 200Ω V <sub>EXT</sub> V <sub>EXT</sub>	Voltage feedback input pin for the external power supply step-down circuit. V <sub>CC</sub> for playback is set by comparing this pin voltage with the internal reference voltage (1.28 V typ.).
11	Vextchg	1.2V - W VEXT-CHG  1.2V - VEXT-CHG  10μA 50kΩ  Λ09985	Voltage feedback input pin for the external power supply step-down circuit. Vcc for charging is set by comparing this pin voltage with the internal reference voltage (1.28 V typ.).
18	Vasp	V <sub>CC</sub> UPBASE	Voltage feedback input pin for the step- up circuit. The step-up voltage is determined by comparing this pin voltage with the internal reference voltage (1.28 V typ.).
19	UPBASE	V <sub>ASP</sub> 50μA 50μΩ 50μΑ 50μΩ A09986	Connection pin for the resistor that is used to set the voltage of the step-up circuit. This prevents invalid current in standby mode.

Pin No.	Symbol	Equivalent circuit	Function
20	Vz	Equivalent circuit	Input pin for start-up circuit when an
_v	.2	Reference voltage startup circuit  S/S  NZ  Reference voltage startup circuit  NZ  Power input Forced startup  NZ  NR  NR  NR  NR  NR  NR  NR  NR  NR	external voltage input is applied. The external voltage input is applied through a resistor inserted in series. The voltage is basically determined 1.2 V + 2V <sub>BE</sub> ; this pin has a current draining capacity up to 20 mA.
27	S/S	\$1.3kΩ 117 117 117 117 117 117 117 117 117 117	LB8118M start-up input. (Start on a low-level input.)
23	V <sub>LD</sub>	VLD VAPC	Laser diode voltage detection pin. The V <sub>LD</sub> voltage +0.5 V is V <sub>APC</sub> .
24	Vapc	50µA	Voltage feedback input pin for the APC step-up voltage circuit.  The step-up power supply voltage is determined by comparing this input voltage with V <sub>LD</sub> .
16	V <sub>O</sub> SET	VCD Voset Voset Ao9989	H bridge power supply limiter voltage pin for the V <sub>OUT</sub> 2 side. The voltage is limited at approximately 190% of the V <sub>O</sub> SET voltage. The setting is made by a dividing resistor.
13	CHG-ON	VCD VCD VCC ↑ ↑ ↑ 20μΑ  20μΑ V <sub>CC</sub> 20μΑ Θ	Pin for selecting battery charging when external voltage input is applied. This pin is used to determine the drop voltage for the external voltage input. When low, the drop voltage set by VEXT is selected; when high, the drop voltage set by VEXT-CHG is selected.
28	MUTE	60kQ MUTE 60kQ	Input pin for simultaneously muting the four-channel drivers. Mute when turning the power on. (Low level: mute)
44	1ch/2ch	SLMODE CHG-ON CHG-ON 80kΩ 80kΩ 80kΩ 80kΩ 80kΩ 80kΩ 80kΩ 80kΩ	This pin is used to switch the H bridge power supply between two-channel simultaneous operation and one-channel operation. (Two-channel operation is selected when this pin is low.)
34	SLMODE		Pin for switching the sled driver between V-type control and step control. (High: V-type control; low: step control)

Pin No.	Symbol	Equivalent circuit	Function
26	Vcc	·	Power supply voltage pin.
29 33	SLREF IN4	VCD VCD VCD VCD VCD VCD VCD VCD	Threshold input pin for driving the sled motor stepwise. Both the positive and negative step levels (with positive-negative symmetry) are determined by thevoltage differential between the pin voltage and the ASPREF pin voltage. (See Supplementary Explanation.)
39	PGND		Output Tr. GND for the four-channel H bridge drivers. This pin is not internally connected to the small-signal system GND.
21	ВО	VCC	Battery check comparator output. Internal output current is 100 μA.
22	ВІ	О.7V VCC VCC 50µА VCC УСС 50µА ВІ ЛО9993	Battery check comparator input. Input bias current is 200 nA or less.

## LB8118M Block Diagram



## **LB8118M Sample Application Circuit**

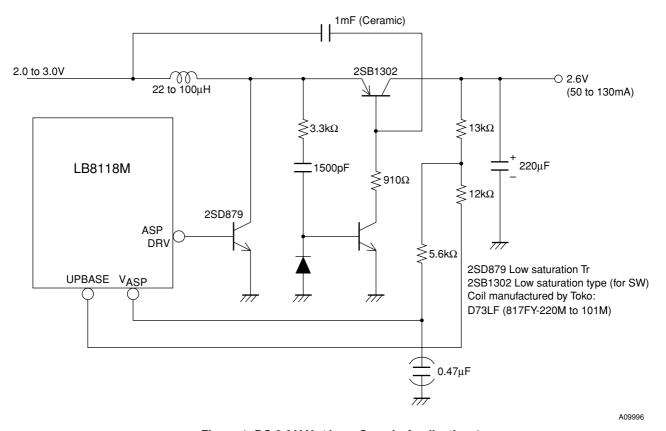


Figure 1 DC 2.6 V Up/down Sample Application 1

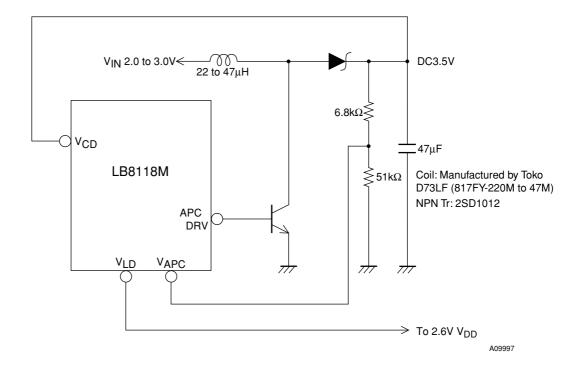


Figure 2 DC 3.5 V Sample Application (when laser power supply is V<sub>DD</sub>)

#### **Supplementary Explanation**

#### 1. VCD supply

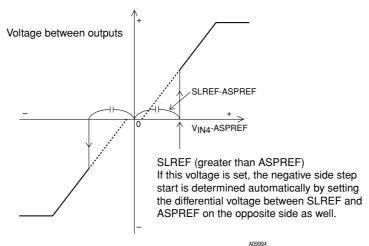
The  $V_{CD}$  line is the power supply for the driver control blocks of channels 1 to 4. The  $V_{CD}$  line can be supplied from the DSP or ASP step-up circuit by using a coil with center tap.

However, because the allowable operating range for  $V_{CD}$  is 3.6 V to 9.0 V, it is recommended that in order to reduce power dissipation, the voltage should be set to the lower range. (Even if this power supply does not affect the control performance such as the transfer gain.)

#### 2. Sled step drive

Stepping control in this IC for the sled actuator is as described below. Normal V-type control is selected if the SLMODE pin is set high, but by setting this pin low, step drive mode with low power dissipation can be selected. (This only affects channel 4.)

The step drive starting level is input from the SLREF pin (must be higher than ASPREF), and the positive side step start is determined by comparing the input voltage with IN4. For the negative side, the step start is determined automatically by setting the differential voltage between the SLREF and the ASPREF on the opposite side, and then comparing that voltage to IN4. In other words, the control characteristics become as defined by the solid line in the diagram below. (The rise on the positive and negative steps has no hysteresis.)



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